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ABSTRACT

Due to both their easy processability and compatibility with roll-to-roll processes, polymer electronics is considered to be the most promising technology for the future generation of low-cost electronic devices such as light-emitting diodes and solar cells. However, the state-of-the-art deposition technique for polymer electronics (spin-coating) generates a high volume of chlorinated solution wastes during the active layer fabrication. Here, we demonstrate that devices with similar or higher performances can be manufactured using the push-coating technique in which a polydimethylsiloxane (PDMS) layer is simply laid over a very small amount of solution (less than 1µl/covered cm²) which is then left for drying. Using mm-thick PDMS provides means to control the solvent diffusion kinetics (sorption/retention) and removes the necessity for additional applied pressure to generate the desired active layer thickness. Unlike spin-coating, pushcoating is a slow drying process which induces a higher degree of crystallinity in the polymer thin film without the necessity for a post-annealing step. The polymer light-emitting diodes and solar cells prepared by push-coating exhibit slightly higher performances with respect to the reference spin-coated devices while at the same time reducing the amounts of active layer materials and chlorinated solvents by 50 times and over 20 times, respectively. These increased performances can be correlated to the higher polymer crystallinities obtained without applying a post-annealing treatment. As push-coating is a roll-to-roll compatible method, the results presented here open the path to low-cost and ecofriendly fabrication of a wide range of emerging devices based on conjugated polymer materials.

1. Introduction:

Polymer light-emitting devices (PLEDs) and solar cells (PSCs) have been developing over the past decade with a large number of publications emphasizing their potential for low-cost electronic device fabrication with efficiencies on par with their state-of-the-art inorganic counterparts. PLEDs and more generally organic LEDs are successfully tackling the mobile display market thanks to their several advantages over conventional display devices, including fast response time, high brightness and contrast, low power consumption, flexibility and lightweight. Similarly, PSCs now reach power conversion efficiencies (PCE) overcoming the milestone value of 10% and closing the gap with the state-of-the-art amorphous silicon solar cells. 14-17

While spin-coating is the most explored film deposition technique on a lab scale due to the simplicity of its use, it is possibly the least suited process to efficiently manufacture large-scale PSCs and PLEDs. To realistically reduce the production cost by using high-productivity technologies such as the roll-to-roll process, finding the adequate method (ideally performed in air and reducing the use of chlorinated solvents) is essential. The need for scalable printing and coating techniques have recently led to explore other approaches such as contact printing, screen printing and inkjet printing, which have successfully been applied both in PLEDs and in PSCs. In 2012, Ikawa *et al.* developed a process referred to as push-coating in which a small amount of solution is deposited on a substrate and then covered by a multilayer elastomer resulting in the formation of homogeneous poly(3-hexylthiophene) (P3HT) layers which are consequently used as active layers for the fabrication of large-scale and low-cost organic field-effect transistors (OFETs). This innovative active layer fabrication approach is a two-step process in which a homogeneous wet polymer layer is firstly formed by capillarity, followed by a solvent drying step (solvent diffusing through the

elastomeric material). A particular attention was given to the development of the elastomeric material (referred to as the stamp) to control the solvent diffusion kinetics. In particular, Ikawa *et al.* emphasized that the stamp should have adequate solvent retention properties to allow for easy removal without damaging the surface of the active layer at the end of the deposition process. The strategy used to generate such solvent retention properties was to develop a poly(dimethylsiloxane) (PDMS) based trilayer stamp in which a fluorocarbon polymer with solvent diffusion barrier properties is sandwiched between two micrometer thin PDMS layers.

Some alternative deposition process to spin-coating have already demonstrated high potential when it comes to reducing the amount of used active material and solution. For instance, the amount of material used during spray-coating has been proven to be 4 times lower than that necessary for the spin-coating process.²⁴ Spraycoating not only considerably reduces the amount of material waste but also very importantly the amount of solvent used in the process as, unlike spin-coating, only a small amount of solution is deposited outside of the substrate (wasted material and solvent). Similarly to blade coating and inkjet printing, push-coating does not generate any active material waste during the deposition, which makes it an eco-friendly process.²⁵ Based on our experiments, push-coating allows for further reducing the amount of active layer materials and chlorinated solvents by factors of approximately 50 and 20 with respect to spin-coating, respectively. Additionally, unlike the above mentioned coating processes, it has the potential to easily trap and recycle chlorinated solvents which are retained in the PDMS stamps. In particular, chlorinated solvents have been proven to have short-term and long-term effects on both the environment and the human health. Recent studies on PSCs have been focusing on reducing as much as possible their usage during device fabrication by, for instance, using green solvent processable active materials²⁶ or water-based microemulsions instead of chlorinated solutions.²⁷ While push-coating considerably reduces the use of chlorinated solvents, the previously designed trilayer stamp introduces additional preparation steps and fluorinated materials (which may also have negative effects on the environment). The study by Ikawa et al. also underlines the fact that, given the slower drying kinetics of the solution during push-coating, molecular rearrangement is favored which increases the amount of crystalline transformation of conjugated polymers in P3HT films obtained by push-coating as compared to their spin-coated equivalents.²³ The increased crystalline transformation may also partially be related to nano-confinement effects (conjugated polymer film trapped between substrate and PDMS) as observed in the case of nanoimprint lithography where, unlike push-coating, the surface patterning and the control over crystallization are obtained by pressing a PDMS stamp on a solid film, while heating.²⁸ The combination of these two phenomena provides us with the possibility to form films with higher crystallinitiy degrees at much lower temperatures. Recently, a second attempt to use push-coating for electronic device fabrication resulted in the generation of PSCs with PCEs up to 2.65 % (as compared to 3.94% for the reference spin-coated devices).²⁹ These promising results, obtained by using extremely thin single layer PDMS stamps, demonstrated that push-coating can be applied not only to OFET fabrication but also to PSCs. However, the push-coated devices displayed much lower device performances compared to the spin-coated reference devices and the reproducibility of the photovoltaic performances was rather low with the necessity to use weights on top of the stamps during the process (decreased control over the process).

Here, we study the push-coating process using single layer PDMS stamps and varying the PDMS stamp thickness to increase the control over the active layer deposition of PLEDs and PSCs. In particular, by analyzing thickness-dependent

diffusion rates in PDMS of two typically employed solvents, we were able to optimize the process conditions and to correlate the diffusion rates with the device performances yellow-green in standard **PLEDs** based on poly(9,9-dioctylfluorene-*alt*benzothiadiazole) (F8BT). The solvents used for this study were chlorobenzene (CB) and dichlorobenzene (DCB). We found that, in devices fabricated by push-coating using less than 1 µl of active layer solution/covered cm², external quantum efficiencies (EQEs) and luminous efficiencies (LEs) are equivalent or higher to those obtained for spin-coated devices. To our knowledge, this is the first time that push-coating processing is applied to PLED fabrication. In addition, in push-coated P3HT:phenyl-C61-butyric acid methyl ester (PCBM) PSCs, we obtained, without annealing steps, similar or higher performances compared to annealed spin-coated active layer devices. Unlike previous studies on push-coated PSCs, we therefore demonstrate that devices with similar performances to spin-coated devices can be obtained by simply adjusting the thickness of the PDMS used for this eco-friendly and roll-to-roll compatible process.

2. Experimental Section:

2.1. PDMS stamp fabrication and solvent diffusion properties

PDMS elastomer (Sylgard 184) was purchased from Dow Corning. To fabricate the stamps, the PDMS precursor was mixed with the curing agent (10:1 weight ratio) and stirred using a glass micropipette. After degassing the mixture to remove air bubbles formed during stirring, standard glass Petri dishes with polished surface were used for the mixture deposition and stamp fabrication at 80°C for at least two hours. The thickness of the PDMS stamps was controlled by the volume of mixture deposited on the cleaned Petri dishes. As an example, to prepare a 7 cm diameter stamp of the wanted thickness, 0.35 g of PDMS prepolymer per 1 mm of thickness were poured in a

glass Petri dish with diameter of 7 cm. The resulting weight of such stamps is about 4 g for each mm of thickness.

Solvent diffusion properties were characterized using two different methods and three different solvents (water, CB and DCB) at room temperature and 50°C. The first method consisted in immersing the PDMS stamp into the various solvents (absorption) or letting it dry (desorption) for a given amount of time and measuring the relative weight variation to extract absorption and diffusion rates. The second method consisted in depositing 25 x 25 mm² PDMS stamps with various thicknesses (2, 3 and 4 mm) on 3 µL of test solvent (water, CB and DCB) for 5 min at room temperature or 50°C. The weight variation of the PDMS stamps before and after the test allowed us to extrapolate the amount of solvent retained for each PDMS stamp thickness and experimental condition.

2.2. Device preparation and characterization

Following a standard cleaning procedure, 40 nm thick poly(3,4-ethylene dioxythiophene):poly(styrene sulfonate) (PEDOT:PSS, Clevios AI4083) layers were spin-coated on ITO covered glass substrates and consequently annealed at 150°C for 10 min. The active layer solutions for push-coating process were prepared in either CB or DCB at concentrations of 10 and 20 mg/ml for F8BT and P3HT:PCBM, respectively. Note that the push-coated organic layers were prepared in air. For spin-coating, the solution concentrations were increased to 20 and 30 mg/ml, for F8BT and P3HT:PCBM respectively. The P3HT:PCBM ratio in both PSC active layer solution was kept at 1:0.8. For active layers deposited on glass/ITO/PEDOT:PSS substrates (25 x 25 mm²), volumes of 3 and 80 μL of solution were used for push-coating and spin-coating, respectively. Various spin-coating speeds for F8BT deposition were used to obtain a

range of active layer thicknesses while P3HT:PCBM active layers were optimized at a thickness of 110 to 130 nm obtained at 800 rpm for 60s. The spin-coated P3HT:PCBM active layers were annealed at 140 °C for 10 min prior to electrode deposition to enhance their photovoltaic performances. The devices were finalized by evaporating Ba/Al and LiF/Al electrodes, respectively for PLEDs and PSCs, prior to an encapsulation step to prevent photo-oxidation of the devices. For PLEDs, electroluminescence (EL) spectra were measured using CCD combined with monochromator (Spex 270M) and applying constant bias between 3 and 12 V. The current density-voltage-luminance (J-V-L) characteristics were recorded with a Keithley 2602 source meter. Light emitted from the devices was detected in forward direction using a calibrated photodiode. Thicknesses of the devices were measured with a Dektak XT (Bruker) profilometer. The encapsulated PSCs were characterized using a source meter (Keithley 2401) and a solar simulator (AM 1.5G, 100 mW/cm²) at room temperature to extract their photovoltaic performances.

2.3. Morphological characterizations

AFM investigations were performed using a NT-MDT NTEGRA apparatus in tapping mode under ambient conditions. X-ray diffraction patterns (XRD) carried out in Bragg-Brentano geometry were obtained at 20 °C using a Siemens D-500 diffractometer equipped with a sensible detector (VORTEX), Soller slits (2°) and narrow slits (0.3°), and a Siemens FK 60-10 2000W tube (Cu K_{α} radiation, λ = 0.154 nm). The operating voltage and current were 40 kV and 40 mA, respectively. Data were collected from 3° to 30° (20) at 0.05° intervals (9s for each one).

3. Results and Discussions:

3.1. Solvent retention in mm thick PDMS stamps

Previous attempts for push-coating were based on the use of very thin PDMS layers either consisting of single PDMS layers or PDMS-fluoropolymer-PDMS trilayers. 23, 29 In the trilayers, the fluoropolymer acts as a solvent blocking layer (no solvent diffusion), allowing for the retention of the solvent in the lower part of the stamp which is in contact with the generated polymer layer. This approach induces facile removal of the stamp after the thin flat film is formed and prevents damage to the film surface while increasing the film homogeneity. In fact, the results for PSCs prepared using push-coating with 80-100 nm thick PDMS single layers exhibit a lower degree of reproducibility as the solvent quickly escapes from the top part of the PDMS leaving an entirely dry PDMS/active layer interface prior to PDMS removal which may damage the active layer surface. Additionally, due to the solvent sorption and desorption kinetics, when exposed to chlorinated solvents, nanometer thin PDMS stamps with low mechanical properties will have a tendency to buckle which further decreases the homogeneity of the generated films, in particular, for large scale device preparation (see Supporting Information, Figure S1). To ensure that PDMS generates a homogeneous contact with the deposited solution on the substrate surface, previous studies on push-coating were performed with additional weight/pressure on top of the stamps.

Our approach is to fabricate thicker PDMS films (thickness on the millimeter scale) and study their sorption/desorption kinetics with the solvents commonly used for organic electronic device preparation. In thicker PDMS stamps, the solvent diffuses over larger distances from the bottom surface (in contact with the wet polymer layer) to the top surface (in contact with air) resulting in a larger quantity of solvent remaining

trapped inside the stamp for relatively short push-coating times. As the single layer PDMS is produced in a single mixing/curing process and as thicker stamps can be prepared without the application of pressure by simply controlling the thickness with the volume inserted in the Petri dishes, the fabrication process of our stamps is much simpler than the ones presented in the previous studies. Last but not least, the thickness of the PDMS not only controls the solvent diffusion kinetics but also provides some weight and enhanced mechanical properties to the stamp, which facilitates the implementation of this roll-to-roll compatible process by removing the necessity for additional applied pressure.

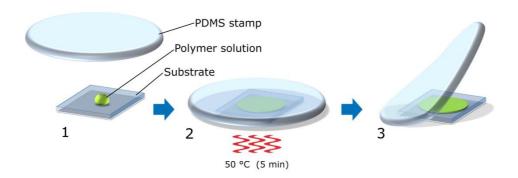


Figure 1. Schematic representation of the push-coating process. A droplet of the semiconducting polymer solution is placed on the substrate and the single-layer PDMS stamp is applied on top of it (step 1); the assembly is heated at 50 °C for 5 min (step 2) and then the PDMS stamp is peeled off leaving a whole thin film on the substrate (step 3).

As depicted in **Figure 1**, in our simplified push-coating approach to fabricate polymer electronic devices, the active layer deposition consists in applying a 2-4 mm thick PDMS monolayer stamp on a 3 μ L droplet of polymer solution pre-deposited on the glass/ITO/PEDOT:PSS substrate (step 1), followed by heating of this assembly at moderate temperature (step 2) and finally peeling off the PDMS stamp (step 3). To verify whether our approach using thicker PDMS stamps can be applied to push-coating,

we first studied the solvent retention abilities of 3 mm thick PDMS films. By soaking the PDMS stamps into CB, DCB and water for up to 10 min and drying them in air for up to 25 min (**Figure 2**), we observed that both sorption and desorption of CB into/from PDMS occur at a much faster rate compared to DCB. However, after 10 min of soaking, both solvents seem to be approaching a saturation level suggesting that less DCB can be absorbed by PDMS as compared to CB. Furthermore, although no major changes can be observed for sorption at room temperature and 50 °C for either CB or DCB, the desorption kinetics seem to be highly dependent on the drying temperature for both chlorinated solvents. Note that water does not diffuse inside the PDMS stamps even when the stamp is soaked in water at 50°C for 10 min.

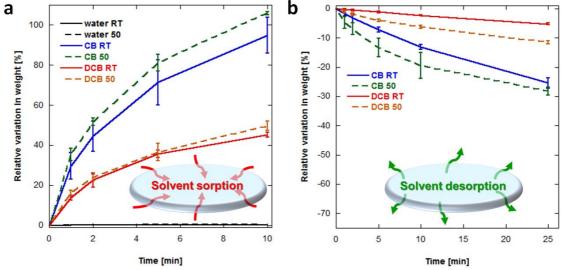


Figure 2. Solvent sorption (a) and desorption in air (b) measured on 3 mm thick PDMS stamps at room temperature (RT) and at 50 °C (50). The error on each experimental data was calculated by repeating the experiment 4 times and the plotted data correspond to the average value of the four experiments.

This suggests that push-coating is limited to solvents displaying the adequate PDMS surface wetting properties. However, unlike chlorinated solvents (toxic to both environment and humans), water and other common polar solvents (such as alcohols) are considered eco-friendly and therefore, reducing their usage is not as essential as reducing chlorinated solvent usage. These results also suggest that the ideal conditions

for push-coating (solvent remaining in the PDMS stamp to avoid surface damage and ease the stamp removal process) should be more likely obtained with DCB at 50 °C and CB at room temperature as the PDMS stamp is neither saturated with solvent nor dry. In fact, during the actual push-coating process, the amount of solvents used is rather low and therefore, to maintain high levels of solvent inside the PDMS stamps, a slow desorption rate (e.g. DCB at 50 °C) may be ideal. However, if the desorption rate is too slow (e.g. DCB at room temperature), the wet PDMS surface in contact with the dried active layer film may damage its surface (partial transfer of the active layer on the PDMS stamp upon removal).

To verify how much solvent remains inside the PDMS layer at the end of the process and assess the effect of the stamp thickness, we measured the weights of solvent included in PDMS stamps with thickness of 2, 3 and 4 mm deposited on 3 µl of solvent. The PDMS stamps were left on the solvent droplet for 5 min at either room temperature or 50 °C. We selected a time of 5 min to ensure that no solvent remains between the substrate and the PDMS stamp. The results are summarized in **Table 1**.

Table 1. Solvent remaining (%) in PDMS stamps with increasing thickness. ^a

	2 mm	3 mm	4 mm
CB (RT)	78±3	93±1	97±2
CB (50 °C)	39±5	75±3	87±3
DCB (RT)	85±3	97±1	98±1
DCB (50 °C)	54±4	79±2	87±2

^a The error displayed in the table corresponds to the variability obtained on three experiment repetitions.

These experiments confirm that, due to the slower sorption/desorption kinetics of DCB inside PDMS, DCB is retained within thinner PDMS stamps (2 and 3 mm thick) much more easily compared to CB. On the other hand, in thicker films, due to longer diffusion ranges, similar results can be observed for both CB and DCB. Results at 50 °C provide a wider range of solvent retention capacity, therefore representing the

ideal system to study the effect of solvent retention on the quality of the produced films. The differences observed for the 2 mm thick PDMS for CB and DCB at 50 °C (39 and 54 % of solvent remaining in the PDMS stamp for CB and DCB, respectively) suggest that, in the case of CB, the solvent quickly moves away from the surface in contact with the substrate. Therefore, we expect to have a higher degree of control for films prepared from DCB as compared to those prepared with CB, in particular when using 2 mm thick PDMS stamps.

3.2. Process control in push-coated PLEDs

To assess the applicability of push-coating to solution processed PLEDs, we chose the widely used F8BT as semiconducting light-emitting material for the active layer. The process was performed following the conditions schematized in Figure 1, including the 5 min heating at 50 °C as this step provides the best conditions and highest film quality for push-coating. At the end of the process, the polymer thin films are entirely dry and we did not observe any remaining polymer film or solution on the PDMS used for the thin film fabrication (Figures S2a-b and S3). The slower diffusion of DCB inside PDMS provides a more controlled film formation process as compared to CB. In fact, in films produced using CB, coffee-ring effects typically attributed to fast drying conditions can be observed which are not present in the case of thin films processed with DCB (Figure S4). As DCB solutions produced quite uniform F8BT films while those push-coated from CB sometimes showed some inhomogeneity, we employed DCB for processing F8BT PLEDs. Furthermore, the higher degree of homogeneity obtained with DCB confirms that the push-coating process is generally better controlled when DCB is used, as suggested by the solvent retention tests performed on pure solvents (Figure 2 and Table 1).

To fabricate a fully functional PLED, it is important to control the active layer thickness. In fact, for an efficient light emission from the device, the optimum thickness of the semiconducting polymer layer is essential, since it can affect both electrical and optical device characteristics, such as the charge carrier transport and, consequently, the efficiency and color.³⁰ In our push-coating approach, the thickness of the PDMS stamp has a direct influence on the thickness of the F8BT film. This is not only related to the different pressure that stamps having different weights naturally apply on the polymer solution but also to the different drying kinetics when using PDMS with various thicknesses. In fact, a slower drying process and higher applied pressure (thicker PDMS) will induce the spreading of the solution over a larger area as compared to push-coating performed with thinner PDMS stamps.

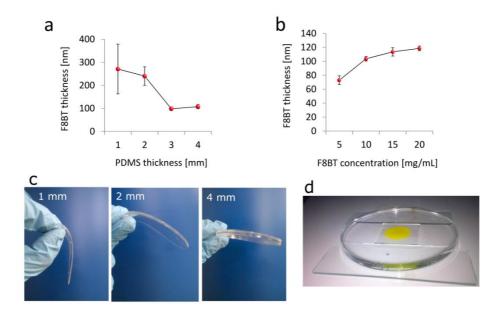


Figure 3. a) Dependence of active layer thickness on the thickness of PDMS stamp. b) Dependence of active layer thickness on polymer concentration, using a 3 mm PDMS stamp. In both plots, the error bars indicate the thickness variability on eight different points on the same film. c) Photographs of 1, 2 and 4 mm thick PDMS stamps, showing different stiffness. d) Photograph of a push-coated F8BT film during the processing.

As shown by the plot in **Figure 3a**, by push-coating a 10 mg/mL F8BT solution in DCB, the active layer thickness decreases from around 300 to around 100 nm by increasing the PDMS thickness from 1 to 4 mm. Because no further pressure than that due to the weight of the stamp is applied in the process, a PDMS stamp of 1-4 mm of thickness generates an applied pressure of about 9.8-39.2 Pa. Another important outcome of this test is that the thickness variability, calculated by repeating the measurement in eight different points on the same film, is much higher in the 1 mm PDMS stamp than in the 2 mm one, while it is very small for the 3 and 4 mm stamps, which provide very similar results. This can be explained by the synergy of two effects: the larger solvent amount retained by thicker stamps which, as assessed before, provides an improved process control; and the change in mechanical properties with PDMS thickness. The growing stiffness and weight observed for 1, 2 and 4 mm stamps (Figure 3c) correlates well with the enhancement in thickness homogeneity/reproducibility of the F8BT film (Figure 3a). Additionally, thinner PDMS stamps have a tendency to buckle during solvent diffusion which further decreases the control over uniform film formation (Figure S1). Consequently, the stiffer the stamp is, the flatter its surface will stay when put in contact with the polymer solution, guaranteeing homogenous spreading and final film formation, as seen in the photograph shown in **Figure 3d**.

While the stamp thickness controls film uniformity and thickness range in the push-coating process, the semiconducting polymer concentration provides finer thickness tunability. As an example, the plot in **Figure 3b** shows the film thickness variation obtained by push-coating F8BT solutions in DCB at different concentrations (5, 10, 15 and 20 mg/mL) with a 3 mm PDMS stamp; by adjusting F8BT concentration, the active layer thickness is well tuned from 70 to 120 nm, a typical thickness range for organic electronic devices. It is also worth noticing that, using a 2 mm stamp and

properly adjusting the polymer solution concentration, active layers of 300 nm of thickness, within 10% of variability, can be produced by our method. These cannot be easily obtained by spin-coating as the thickness is limited by the polymer solubility in organic solvents and by the necessity for high rotating speeds to generate large scale homogeneous films.

3.3. Processable area size limit and reusability of PDMS stamps

To explore further the suitability of our modified push-coated approach for processing large area optoelectronic devices, we prepared a series of F8BT films using different solution volumes, and measured their area with ImageJ software.³¹ Starting from a solution volume of 3 µL, which afforded a film area of about 3 cm², suitable for the preparation of typical prototype devices, we increased the push-coated solution volume until 50 μL, obtaining a film of about 20 cm², as shown in Figure 4a. The plot in Figure 4b displays an almost linear dependence of the film area on the solution volume employed. Such a trend suggests that there are no limits for the maximum processable film area, a promising indication for the introduction of this technique into large-area electronics production. However, as depicted in the plot in Figure 4c, the thickness homogeneity along the four positions indicated in the inset, decreases in large films. This suggests that the fabrication of high quality and large area push-coated films is limited by the thickness homogeneity. A specific process optimization for large films-e.g., by using wider PDMS stamps and an automated system for releasing the stamp on the polymer solution, would therefore be more appropriate to achieve this objective.

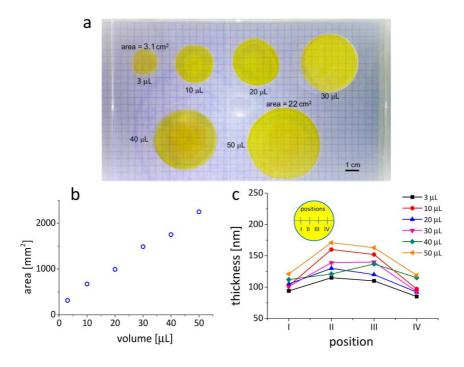


Figure 4. a) Multiple push-coated films prepared on a glass window (20 × 20 cm²) using the same 3 mm thick PDMS stamp and different volumes of 10 mg/mL F8BT solutions in DCB, reported next to each film. The size of smallest and biggest film areas is also reported. The glass window was superimposed over a graph paper sheet to guide the comparison of film areas. b) Dependence of film area on the F8BT volume used. c) Film thickness measured in four different positions (I-IV, shown by the cartoon in the inset) on each film.

Another important issue for assessing the compatibility of push-coating process with roll-to-roll production is the reusability of the PDMS stamps. As a consequence of solvent diffusion in PDMS, immediately after the push-coating process, a swelling area in correspondence with the film is visible on the stamp surface (**Figure S2a**). The swollen stamp is not usable for push-coating until the adsorbed solvent evaporates, restoring stamp to the original flat shape (**Figure S2b**). Moderate heating in oven (80 °C for 10 min in the case of DCB) fasten this process and makes the stamp ready to be reused. To further speed-up the reusability, a hot air jet can be used. Moreover, the solvent trapped in PDMS could be easily collected and recycled.

In order to generate a continuous process, stamp contamination by processed material should be avoided. As shown in **Figure S3**, contamination can be relevant when perylene diimide (PDI), a fluorescent small molecule widely used in organic electronics, is processed. However, when polymers like F8BT are processed, the situation is totally different. The PL analysis of a PDMS stamp after six repeated push-coating process indicated a very small stamp contamination which, anyway, can be almost completely removed by a single washing in DCB. Consequently, push-coating seems to be an adequate process to fabricate thin films of conjugated polymeric materials.

3.4. Increased performances in push-coated PLEDs

Once the process control and film quality of the push-coated F8BT layers were assessed, we tested them in PLEDs. To do this, we compared push-coated and spin-coated devices with the same standard architecture for yellow-green PLEDs (ITO/PEDOT:PSS/F8BT/Ba/Al) and similar active layer thickness. To facilitate a direct comparison, the spin-coated devices were manufactured in air and subjected immediately after deposition to the same mild thermal treatment optimized for the push-coating process, as schematized in **Figure 5a**. The device performances are summarized in **Table 2** and plotted in **Figure 5b** as a function of F8BT thickness (detailed characterization data are also available in the Supporting Information, **Figure S5**).

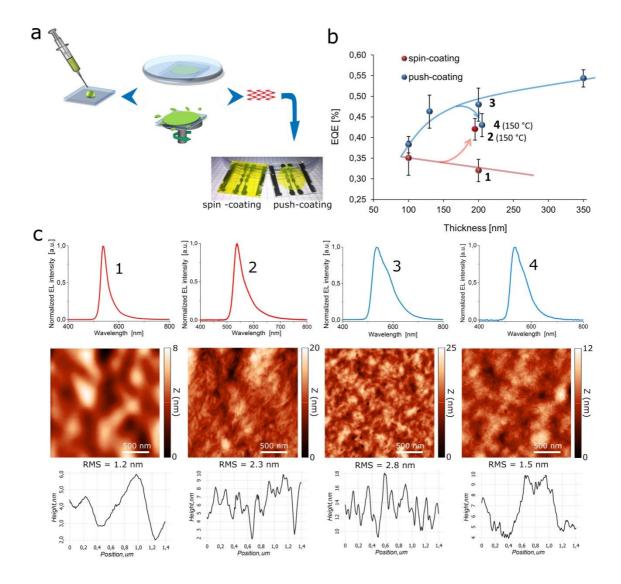


Figure 5. Comparison between push-coated and spin-coated PLEDs. a) Schematic representation of device preparation. b) EQE of different spin-coated and push-coated devices as a function of F8BT thickness and thermal treatment. The error bars were determined from the average efficiencies and their corresponding standard deviations based on four devices. c) Normalized EL spectra (top), surface morphology (middle) and profile (bottom) of four representative devices with 200 nm active layer thickness: (1) spin-coated, (2) spin-coated and annealed at 150 °C for 30 min, (3) push-coated, and (4) push-coated and annealed at 150 °C for 30 min.

Table 2. Spin-coated and push-coated F8BT PLED performances.

Device type (thickness)	V _{on} (V)	EQE max ^a (%)	EQE @ 50mA/cm ^{2 a} (%)	LE @ 50mA/cm ² (cd/A)	PE @ 50mA/cm ² (lm/W)
spin-coated (100 nm)	2.5	0.35 ± 0.04	0.31 ± 0.03	1.1	0.60
spin-coated (200 nm)	5.0	0.32 ±0.03	0.25 ±0.02	1.0	0.27
push-coated (100 nm)	2.5	0.39 ± 0.02	0.37 ± 0.04	1.3	0.65
push-coated (130 nm)	2.5	0.48 ± 0.04	0.47 ± 0.04	1.7	0.85
push-coated (200 nm)	3.5	0.49 ±0.04	0.46 ± 0.04	1.6	0.36
push-coated (350 nm)	4.0	0.55 ± 0.02	0.55 ± 0.02	2.1	0.37
spin-coated (200 nm) 150°C	6.0	0.42 ±0.03	0.32 ± 0.02	1.2	0.32
push-coated (200 nm) 150°C	3.5	0.43 ±0.03	0.36 ± 0.03	1.3	0.55

^a The error values were determined from the average efficiencies and their corresponding standard deviations based on four devices.

The EQE of spin-coated PLEDs with standard (100 nm) and thicker (200 nm) active layer remained nearly constant around 0.35 %. The corresponding push-coated devices with 100 and 200 nm F8BT thickness both exceeded this efficiency value. Moreover, unlike spin-coated devices, in the push-coated PLEDs we observed a gradual efficiency increase with thickness, and the highest values were obtained for active layer thickness above 300 nm (EQE = 0.55 %, LE = 2.1 cd/A). Consequently, while the efficiency difference between the 100 nm thick devices obtained by the two different processes was narrow (11 % increase in EQE for push-coated devices relative to spin-coated ones), the difference between the 200 nm spin-coated and push-coated PLEDs (53 %) becomes more relevant.

To shed light on the different trends observed, we investigated these devices by spectroscopical and morphological analysis. As shown in **Figure 5c**, all the devices displayed similar electroluminescence (EL) spectra, with the maximum peak located around 540 nm. The PL quantum yield for spin-coated and push-coated F8BT films was quantified as 48 ± 5 % and 50 ± 3 %, respectively, which does not explain the different performances. However, while the device obtained by spin-coating (1) showed a smooth active-layer surface by AFM, with root mean square (RMS) roughness of 1.2 nm, the

push-coated PLED (3) showed a more organized morphology with the polymer arranged in tightly packed fibril-like domains, resulting in a RMS roughness of 2.8 nm.

The post-deposition annealing temperature plays an essential role in determining the morphology of a spin-coated polymer film, 32-34 and therefore, we fabricated spincoated devices (2) prepared under the same conditions as for 1 but which were annealed at 150 °C for 30 min before evaporating the metallic electrodes. As shown by the plot in Figure 5b, the annealed device 2 exhibited intermediate performances with respect to the pristine spin-coated (1) and the push-coated (3) devices, suggesting that the annealing process triggered the enhancement of the polymer packing/self-organization, leading to higher PLED efficiency. This was confirmed by AFM analysis, which evidenced that for the annealed spin-coated film 2 a fibrillar morphology resembling that observed for the push-coated film 3 (see Figure 5c), with the RMS roughness passing from 1.2 to 2.3 nm after the annealing process. In polymer semi-conducting thin films, chain aggregation can have a major impact on the charge transport properties as the charge transport mechanism in these materials relies on both intrachain transport and charge hopping to neighboring chains. Therefore, a more efficient balance between charge transport and recombination within F8BT active layer can be expected in 2 and 3 with respect to 1, which accounts for the different PLED performances.³⁵ In light of these observations, we can ascribe the slightly better performances shown by pushcoating approach with respect to spin-coating, to the slower film formation process which produces a better polymer self-organization, possibly resulting in a modest increase of crystallinity degree (less than 10%, see Figure S6 and S7), without need for thermal annealing. When the push-coated device was subjected to the same annealing process as for 2, we recorded a moderate decrease of the performances (device 4) with respect to the untreated push-coated device (3), together with a roughness diminution

from 2.8 to 1.5 nm, confirming the optimal morphology of the as-deposited push-coated film. It is worth noticing that well-performing PLEDs with active layer thickness over 300 nm cannot be easily obtained by spin-coating and their fabrication in standard architecture has rarely been reported.^{36, 37} Moreover, to fabricate the 200 nm devices, 3 μL of F8BT solution at the concentration of 10 mg/mL and 80 μL of 20 mg/mL solution were used in the push-coating and spin-coating processes, respectively. Fabricating PLEDs by push-coating therefore reduces used active layer material and solvent amounts by factors of 50 and 20, respectively, as compared to spin-coating.

3.5. Enhanced photovoltaic effect in highly crystalline push-coated PSCs

Unlike F8BT, whose amorphous nature limits the possibility for effectively observing changes in crystallinity between push-coated and spin-coated films, much more notable changes are expected when depositing thin films based on the highly regioregular and consequently crystalline P3HT. In fact, the previous study on push-coating of P3HT films for OFET fabrication revealed that the push-coated P3HT films exhibit a higher degree of crystallinity as compared to their spin-coated equivalents.²³ Scientific literature clearly emphasizes that both the post-deposition annealing temperature and the boiling point of the solvent used for active layer deposition play essential roles in determining the morphology of P3HT:PCBM films.^{38, 39} To understand the effect of the solvent (CB or DCB) over the crystallinity and device performances of push-coated P3HT:PCBM PSCs and compare them with spin-coated films, we performed the experiments with 3 mm thick PDMS stamps at 50 °C for 5 min as these process parameters resulted in the optimized active layer thickness for regular PSCs. In spin-coated films, the crystallinity of the polymer:fullerene blend depends on the evaporation rate of the solvent; a higher degree of crystallinity is obtained for slower

evaporation rates. Similarly, in push-coated films, we expect to observe highly crystalline structures when using solvents with a slower diffusion rate inside the PDMS stamp. In our case, this would correspond to DCB which, coincidentally, is also the solvent with the slower evaporation rate.

To determine whether our hypothesis on diffusion rate and crystallinity was valid, we first performed XRD measurements to observe the evolution of the (100) P3HT crystallinity peak in the films prepared using the two solvents by either spin-coating or push-coating (**Table 3** and **Figure S8**).

Table 3. P3HT crystallite characteristics in P3HT:PCBM spin-coated and push-coated films.

	D ₍₁₀₀₎ ^a	$\mathbf{L_{(100)}}^b$	$\epsilon_{\rm rms}^{}$
spin-coated (CB)	1.66	7	-
annealed at 140°C 10 min	1.63	8.5	0.04
spin-coated (DCB)	1.625	9	-
annealed at 140°C 10 min	1.60	14.5	0.028
push-coated (CB at 50°C 5 min)	1.59	13	0.03
push-coated (DCB at 50°C 5 min)	1.57	15	0.026

 $[^]a$ D₍₁₀₀₎ is the interplanar spacing. b L(100) is the crystallite size along the (100) direction. c $\epsilon_{rms} = (\langle e^2 \rangle)^{1/2}$ where $e = \delta d_{(hkl)}/d_{(hkl)}$, is the non-uniform strain, defined as root mean square of the lattice variations in the sample. 35

The results on spin-coated films are well correlated with previous studies as they confirm that larger and more densely packed (shorter interplanar spacing and improved crystallite perfection, i.e. smaller ε_{rms} values) P3HT crystals are obtained in thin films deposited with slower drying conditions (DCB at room temperature) as compared to CB.^{40,41} Note that P3HT:PCBM spin-coated films annealed at 50°C for 5 min (similarly to push-coating conditions) do not exhibit any major difference with respect to unannealed ones. However, upon annealing at 140°C, the crystalline domain size in spin-coated films increase from 7 to 8.5 nm, and from 9 to 14.5 nm for films deposited from CB and DCB, respectively. The push-coated films, on the other hand, readily

display a high crystallinity for both CB and DCB. In fact, although push-coated films from DCB display crystallite dimensions equal to those of annealed DCB spin-coated films, the XRD measurements also reveal that they are more densely packed than the DCB spin-coated annealed films. A shorter interplanar spacing distance reflects stronger π - π interactions between neighboring polymer chains and consequently, more efficient charge transport and collection (increase in fill factor (FF)) is expected for push-coated DCB devices compared to others. Taking into account the interplanar spacing and crystallite dimensions measured by XRD, we therefore expect to obtain increasing device FF in the following sequence (lower to higher): spin-coated annealed CB; push-coated CB; spin-coated annealed DCB (equal or higher to push-coated CB); push-coated DCB.

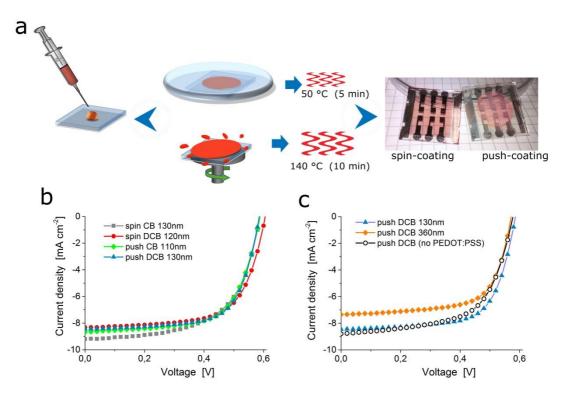


Figure 6. Comparison between push-coated and spin-coated PSCs. a) Schematic representation of device preparation. b) *J-V* characteristics of the spin-coated and push-coated PSCs deposited from CB and DCB. c) Comparative *J-V* characteristics of 130 nm thick P3HT:PCBM PSCs (reference), thicker (360 nm) and simpler (no PEDOT:PSS layer) devices obtained by push-coating.

The device performances (**Figure 6** and **Table 4**) and, in particular, their FF, well correlate with the sequence described above. For devices with active layer thickness in the range of 110~130 nm, the average FF are 59.4, 64.6, 65.0 and 67.2 for spin-coated CB, push-coated CB, spin-coated DCB and push-coated DCB, respectively. Similarly, the PCE of the devices also follow the same trend as the crystallinity measured for the P3HT in the active layer. On the other hand, a slower drying process will not only lead to larger P3HT crystallites but also to larger donor-acceptor domains, which in turn, reduces the donor-acceptor interface area and consequently, the short-circuit current density (Jsc). The open-circuit voltage (Voc) does not change dramatically for all devices except for the spin-coated DCB devices (approximately 20 mV higher than the other devices). This may be due to a variation in vertical P3HT:PCBM concentration gradient leading to a reduction of the reverse saturation current, and consequently, an increase in Voc as observed in other similar systems.³⁹

Table 4. Spin-coated and push-coated P3HT:PCBM PSC device performances.^a

Device type:	Jsc (mA/cm ²)	Voc (mV)	FF (%)	PCE (%)
spin-coated CB (annealed, 130 nm)	9.20	590	59.4	3.23±0.04
spin-coated DCB (annealed, 110 nm)	8.34	608	65.0	3.30±0.05
push-coated CB (130 nm)	8.65	591	64.6	3.30±0.12
push-coated DCB (120 nm)	8.46	589	67.2	3.34±0.09
push-coated DCB (360 nm)	7.44	584	63.7	2.77±0.20
push-coated DCB (no PEDOT:PSS)	8.78	582	60.6	3.10±0.11

^a The error displayed in the table corresponds to the variability obtained on eight devices.

Due to this change in Voc, the increase in PCE from spin-coated to push-coated devices from DCB is of only 0.04% even though the FF increases over 2%. Furthermore, it is worth noticing that push-coated devices with thicker active layers up to 360 nm (3 times more than the commonly used active layer thicknesses in regular devices) still

exhibit FF of approximately 64%, a value similar to that of annealed DCB spin-coated active layers. This suggests that non-homogeneous active layers may still display relatively high device performances which will extremely facilitate the transition from lab scale to roll-to-roll large scale device fabrication. Additionally, we have prepared push-coated DCB devices without the PEDOT:PSS hole transporting layer (which cannot be deposited using push-coating as it is deposited from water-based emulsions). These devices exhibit average PCEs of 3.1%, a value similar to that of spin-coated devices (only 5-10% lower relative PCEs). Note that removing the PEDOT:PSS layer in spin-coated devices usually results in approximately 30% reduction in PCE. Taking into account that thicker active layers and simpler device architectures can be used in push-coated devices which, furthermore, do not require any post-annealing treatment, our devices have a great potential for the low-cost and eco-friendly fabrication of high productivity roll-to-roll PSCs.

4. Conclusions:

In summary, we have demonstrated that push-coating is a versatile method to fabricate active layers for PLEDs and PSCs. In fact, unlike previous studies, our work not only confirms that this method is applicable to many types of organic electronic devices producing performances similar or higher than those of spin-coated devices, but it also introduces the fact that using thicker PDMS stamps for push-coating has a variety of advantages, e.g. removes the necessity for multilayer stamps with nanoscale dimensions, which simplifies the overall process. In fact, the intrinsic mechanical and solvent diffusion properties of PDMS allow for easier preparation and handling of the stamps which can then produce conjugated polymer-based thin films with controllable thicknesses through push-coating. We have demonstrated that a control over the thin film thickness can be achieved with PDMS stamps having thicknesses of at least 3 mm.

Push-coated PLEDs and PSCs were both fabricated using volumes of solutions approximately 20 times lower compared with common polymer layer deposition techniques (spin-coating). Considering also that push-coating generally requires a lower polymer concentration to prepare films of similar thickness as the spin-coated ones, the active layer material waste is remarkably cut down and, consequently, so is the production cost. Moreover, as these layers are usually deposited using chlorinated solvents, push-coating also considerably reduces hazard to both environment and human health.

Our push-coated PLEDs exhibit EQEs up to 0.55% (compared to 0.35% for reference spin-coated devices) with LEs reaching values up to 2.1 cd/A (compared to 1.1). Unlike spin-coated devices, the device performances of push-coated PLEDs increase with thickness which suggests that a different molecular arrangement is obtained in the thin polymer layers prepared using the two deposition techniques, as confirmed by AFM analysis.

When comparing crystallite formation and interchain interaction in P3HT:PCBM films prepared by spin-coating or push-coating, we can clearly observe that a higher degree of order is obtained for the latter. Consequently, our newly developed cost-effective and environment-friendly process allows fabricating PSCs with performances slightly exceeding those of spin-coating devices (3.30 and 3.34 % of average PCEs, respectively for spin-coating and push-coating). Although the PCEs are similar, as push-coating does not require any post-annealing process and can be used to fabricate simpler device architectures (no PEDOT:PSS) without remarkably decreasing the FF, it is an extremely promising deposition technique to produce roll-to-roll PSCs with PCEs of approximately 3% using the state-of-the-art polymer:fullerene

combination materials. In conclusion, we have demonstrated that push-coating is not limited to OFETs and PSCs and, additionally, not limited to a certain number of materials but can be applied to virtually any device architecture and material provided that the solvent diffusion inside the PDMS stamp can be controlled. Therefore, our work opens the path to the fabrication of extremely low-cost electronic devices to provide displays and solar panels to everyone in both developing and developed countries around the planet.

Supporting Information

Comparison between PDMS stamps with different thicknesses exposed to solvent vapors; Reusability tests of PDMS stamps for push-coating; Effect of solvent on push-coated film formation; Comparative opto-electrical characterization of spin-coated and push-coated films; XRD spectra of spin-coated and push-coated films.

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Table of Content Graphic:

